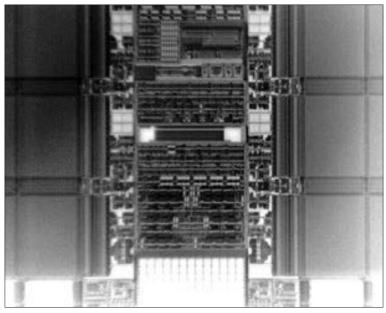
# **Thermal NanoLens**

The Thermal NanoLens brings the advantages of SIL imaging to both downward and upward looking thermal emission microscopes.



▲ Image taken with Thermal NanoLens (See last page for details)

# Features

- Numerical aperture (N.A.): 2.6
  - · Maximum resolution: approx. 1 µm
- Available for both downward looking system and inverted system
- Swappable SIL Cap architecture
  - · Swapping between two types of SIL caps that cover Si thickness from thinned chip to full wafer thickness.
  - · SIL cap is keyed for straightforward mounting.
  - Lens is automatically aligned on a device surface to get the best contact between a lens and Si surface to collect light signal most efficiently.

# Application

- Backside observation of advanced devices
  - · Thermal photoemission analysis









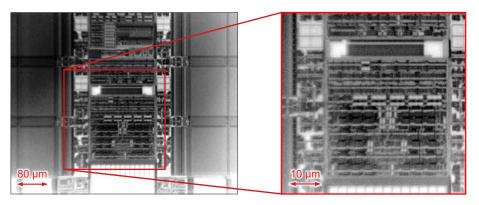
# Failure Analysis Systems Option

### Case study

■ Purpose Evaluation of a Thermal NanoLens resolution by using an actual device

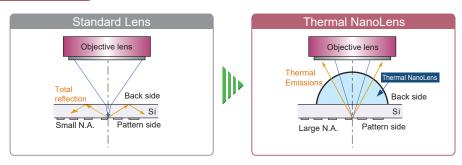
Method Sample: A commercially available 38 nm DRAM with decapsulation. Take a pattern image using an InSb camera

■ Result



Conclusion Acquired image has no distortion. FOV 340 µm × 270 µm The 100 µm × 90 µm size digital zoomed image shows detailed structure clearly.

## Principles



Due to the high reflection index of Si, light passing through the Si layer is not collected efficiently by an objective lens. By putting a Si lens directly on the Si surface, all light that has been reflected at the boundary between Si and the lens can be collected and focused to a high N.A. objective lens. Higher light collection efficiency improves image resolution drastically.

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